

(c) ___

rejection under 37 C.F.R. 1.129(a).

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE					
In re patent	application of				
Applicant: Serial No.: Filed: For: Art Unit: Examiner:	Halliyal et al. 10/731,494 December 9, 2003 IMPROVED PROCESS FOR FABRICATION OF SPACER LAYER WITH REDUCED HYDROGEN CONTENT IN SEMICONDUCTOR DEVICE 2812 Not yet known				
	INFORMATION DISCLOSURE STATEMENT				
P.O. Box 14	ner for Patents 50 VA 22313-1345				
Sir:					
the patents, listed docun	t to 37 C.F.R. 1.97 and 1.98, and in compliance with 37 C.F.R. 1.56, the Office's attention is directed to pending applications, publications and other information listed on the attached PTO-1449. A copy of each nent is enclosed except for: (a) pending applications or (b) those previously cited or submitted to the Office ing application(s) upon which this application relies for an earlier filing date under 35 U.S.C. 120:				
Serial No Filing Da					
Applicant(s)	any document, publication or other information for which a date is not given on the attached PTO-1449, believe(s) the same may qualify as "prior" art to this application and should be treated accordingly, plicant(s) reserve(s) the right to contest the prior art status of any document, publication or information, a arise.				
this Stateme	ng each listed document that is not in the English language, an English-language translation accompanies ent as indicated on the attached PTO-1449 or a concise explanation of the relevance of the document is he following document(s):				
(a)	Copy of each English language version of a search report indicating the degree of relevance found by the foreign office of each document being submitted from the search report.				
(b)	Attachment entitled "Concise Explanation of Relevance of Non-English Language Documents".				
3. Pursuan	t to 37 C.F.R. 1.97(b) this Statement is being filed (one must be checked):				
(a)	Within 3 months of the filing date, date of entry into the National Stage, or filing date of CPA.				
(b) <u>X</u>	Before the mailing date of a first Office Action on the merits. If this Statement is not filed before the mailing date of a first Office Action on the merits, the required certification is given below or, in the absence thereof, the Office is authorized to charge the required fee set forth in 37 C.F.R. 1.17(p) to Deposit Account No. 18-0988 for consideration of this Statement.				

Before the mailing date of a first Office Action on the merits after a first or second submission after final

	(d) _		After the period set forth in 37 C.F.R. 1.97(b) but before the mailing date of either a final action or a notice of allowance.		
	('	1)	The required certification is given below, or		
	(2	2)	Enclosed is a check covering the fee set forth in 37 C.F.R. 1.17(p) for consideration of this Statement, or		
	(3	3)	Charge the fee set forth in 37 C.F.R. 1.17(p) to Deposit Account No. 18-0988		
	(e)_		After the mailing date of either a final action or a notice of allowance, but before payment of the issue fee. Petition hereby is made for consideration of this Statement and the required certification is indicated below.		
	(*	1)	Enclosed is a check covering the fee set forth in 37 C.F.R. 1.17(p), or		
	(2	2)	Charge the fee set forth in 37 C.F.R. 1.17(p) to Deposit Account No. 18-0988.		
1.	Certi	ificatio	on (if applicable)		
	(a) The undersigned hereby certifies that each item of information contained in this Statement was first cit in any communication from a foreign patent office in a counterpart foreign application not more than months prior to the filing of this Statement.				
	(b) _		The undersigned hereby certifies that no item of information contained in this Statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the undersigned's knowledge after making reasonable inquiry, was known to any individual designated in 37 C.F.R. 1.56(c) more than 3 months prior to the filing of this Statement.		
			missioner is hereby authorized to charge any additional fees or credit any overpayment to Deposit 18-0988.		
			Respectfully Submitted,		
			RENNER, OTTO, BOISSELLE & SKLAR, LLP		
			By Monagh alfaul		
			Thomas W. Adams Reg. No. 35,047		
		nd, O	Avenue, 19th Floor Phio 44115		
			CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8		
de	posite	ed on	ify that this correspondence (along with any paper referenced as being attached or enclosed) is being the below date with the United States Postal Service with sufficient postage as first class mail in an dressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.		

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Form \$ TO-1449 (Modified) 2004 µ

LIST OF PATENTS AND PUBLICATIONS
FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

Atty Docket No.	Serial No.			
AF01194	10/731,494			
Applicant: Halliyal et al.				
Filing Date	Group			
12/09/03	2812			

U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date if Appropriate
	5,284,549	02/08/94	Barnes et al.	156	662	
	5,648,113	07/15/97	Barbee et al.	427	8	
-	5,707,901	01/13/98	Cho et al.	438	595	
	5,840,600	11/24/98	Yamazaki et al.	438	51	
	5,872,387	02/16/99	Lyding et al.	257	607	
	5,970,384	10/19/99	Yamazaki et al.	438	795	
	6,022,799	02/08/00	Foote et al.	438	637	
	6,037,003	03/14/00	Gordon et al.	427	255.34	
*	6,180,190 B1	01/30/01	Gordon	427	565	
	6,190,966 B1	02/20/01	Ngo et al.	438	257	
	6,194,784 B1	02/27/01	Parat et al.	257	774	
	6,306,777 B1	10/23/01	Ogle, Jr. et al.	438	763	
	6,319,809 B1	11/20/01	Chang et al.	438	597	
	6,319,775 B1	11/20/01	Halliyal et al.	438	261	
	6,468,599 B1	10/22/02	Terada	427	558	
	6,479,379 B2	11/12/02	Reinberg	438	635	
_	2002/0068229 A1	06/06/02	Westerman et al.	430	5	

FOREIGN PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Country	Class	Sub- class	Translation	
IIIII					Class	Yes	No
				-			

OTHER ART

Examiner Initial	Author, Title, Date, Pertinent Pages, etc.			
	U.S. Patent Application Serial No. 10/731,659 filed December 9, 2003, entitled "PROCESS FOR FABRICATION OF NITRIDE LAYER WITH REDUCED HYDROGEN CONTENT IN ONO STRUCTURE IN SEMICONDUCTOR DEVICE."			

Examiner Initial	Author, Title, Date, Pertinent Pages, etc.				
EXAMINE	ER	DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Information Disclosure Statement PTO-1449 (Modified)

The identification of any reference is not intended to be, and should not be understood as being, an admission that such publication, in fact, constitutes "prior art" within the meaning of applicable law since, for example, a given reference may have a later effective date than first seems apparent or the reference may have an effective date which can be antedated. The "prior art" status of any reference is a matter to be resolved during prosecution.

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